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MOSFET - Power, DUAL COOL[®] N-Channel DFN8 5x6 60 V, 1.5 mΩ, 224 A NVMFSC1D6N06CL

Features

- Advanced Dual-sided Cooled Packaging
- Ulra Low R_{DS(on)}
- MSL1 Robust Packaging Design
- AEC-Q101 Qualified

Typical Applications

- Orring FET/Load Switching
- Synchronous Rectifier
- DC-DC Conversion

MAXIMUM RATINGS (T_J = 25°C unless otherwise noted)

Parameter			Symbol	Value	Unit
Drain-to-Source Voltage			V _{DSS}	60	V
Gate-to-Source Voltage	Gate-to-Source Voltage			±20	V
Continuous Drain	Steady State	$T_{C} = 25^{\circ}C$	Ι _D	224	А
Current $R_{\theta JC}$ (Note 2)		$T_{C} = 100^{\circ}C$	Ι _D	158.6	А
Power Dissipation	Steady State	$T_{C} = 25^{\circ}C$	PD	166	W
$R_{\theta JC}$ (Note 2)		T _C = 100°C	PD	83	W
Continuous Drain Current R _{θJA} (Notes 1, 2)	Steady State	T _A = 25°C	۱ _D	35	А
		$T_A = 100^{\circ}C$	Ι _D	24.8	А
Power Dissipation	Steady State	T _A = 25°C	PD	4.1	W
$R_{\theta JA}$ (Notes 1, 2)		T _A = 100°C	PD	2	W
Pulsed Drain Current	$T_A = 25^{\circ}C, t_p = 10 \ \mu s$		I _{DM}	900	А
Operating Junction and Storage Temperature Range			T _J , T _{stg}	–55 to +175	°C
Source Current (Body Diode)			I _S	164	А
Single Pulse Drain-to-Source Avalanche Energy (I _{L(pk)} = 17 A)			E _{AS}	451	mJ
Lead Temperature Soldering Reflow for Solder- ing Purposes (1/8" from case for 10 s)		ΤL	300	°C	

Stresses exceeding those listed in the Maximum Ratings table may damage the device. If any of these limits are exceeded, device functionality should not be assumed, damage may occur and reliability may be affected.

THERMAL RESISTANCE MAXIMUM RATINGS

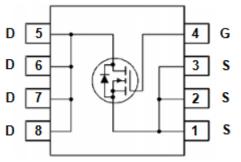
Parameter	Symbol	Value	Unit
Junction-to-Case - Steady State (Note 2)	$R_{\theta JC}$	0.9	°C/W
Junction-to-Ambient - Steady State (Note 2)	$R_{\theta JA}$	37	

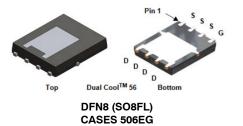
1. Surface-mounted on FR4 board using a 1 in² pad size, 1 oz Cu pad.

The entire application environment impacts the thermal resistance values shown, they are not constants and are only valid for the particular conditions noted.

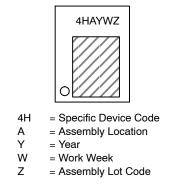
V _{(BR)DSS}	R _{DS(ON)} MAX	I _D MAX	
60 V	1.5 mΩ @ 10 V	224 A	
	$2.3~\mathrm{m}\Omega$ @ $4.5~\mathrm{V}$	224 A	

N-Channel MOSFET





MARKING DIAGRAM



ORDERING INFORMATION

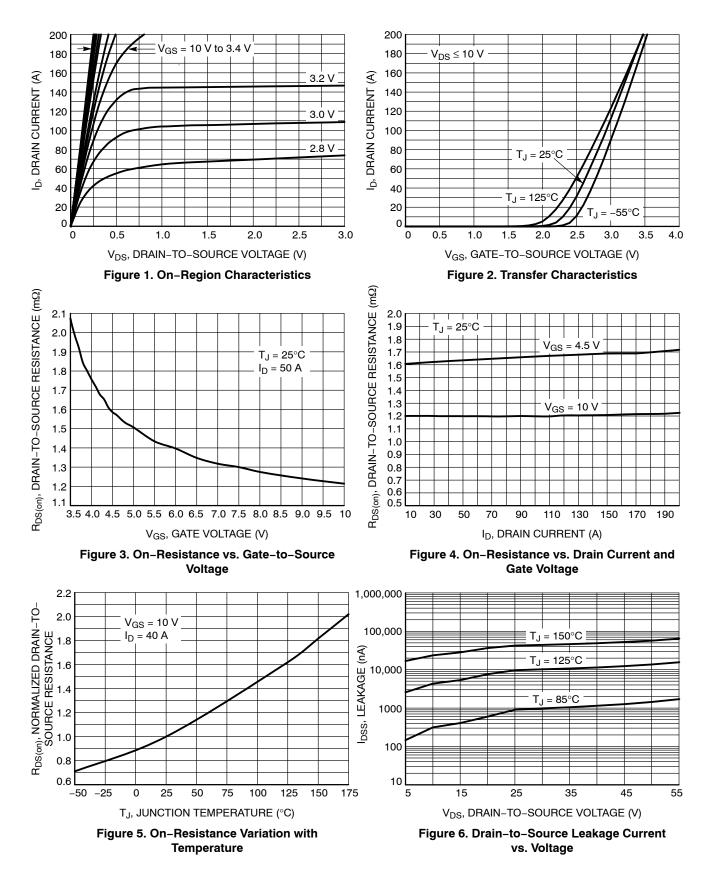
See detailed ordering, marking and shipping information on page 5 of this data sheet.

ELECTRICAL CHARACTERISTICS (T_J = $25^{\circ}C$ unless otherwise specified)

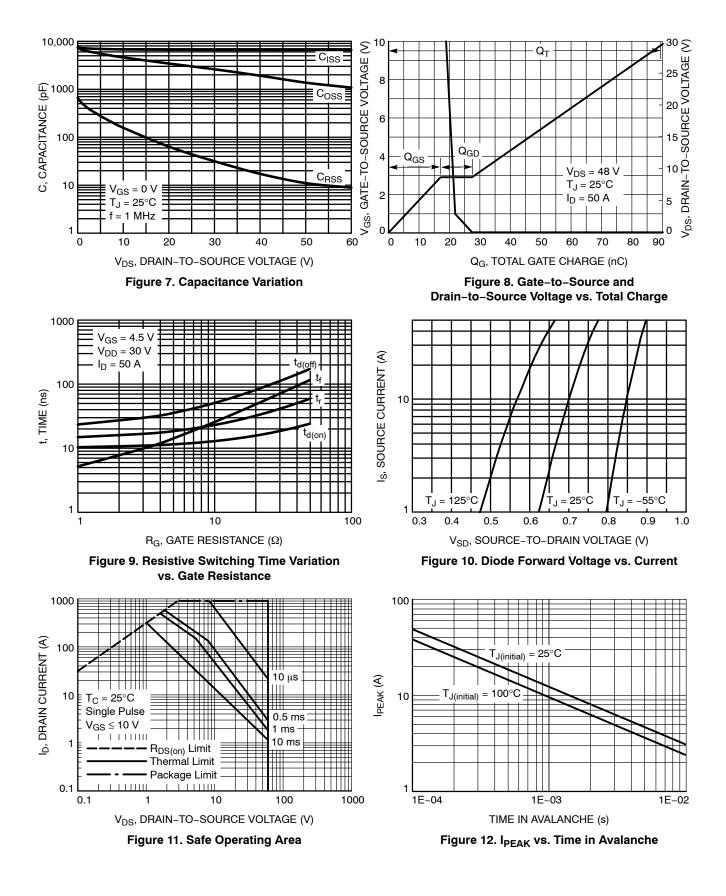
Parameter	Symbol	Test Condition		Min	Тур	Max	Unit
OFF CHARACTERISTICS				-		-	
Drain-to-Source Breakdown Voltage	V _{(BR)DSS}	$V_{GS} = 0 V, I_D = 250 \mu A$		60			V
Drain-to-Source Breakdown Voltage Temperature Coefficient	V _{(BR)DSS} / T _J	I_D = 250 µA, ref to 25°C			12.7		mV/°C
Zero Gate Voltage Drain Current	I _{DSS}	V _{GS} = 0 V, V _{DS} = 60 V	T _J = 25°C T _J = 125°C			10 100	μΑ
Gate-to-Source Leakage Current	I _{GSS}	V _{DS} = 0 V, V _{GS}				100	nA
ON CHARACTERISTICS (Note 3)							
Gate Threshold Voltage	V _{GS(TH)}	$V_{GS} = V_{DS}, I_D =$	250 μΑ	1.2		2.0	V
Negative Threshold Temperature Coefficient	V _{GS(TH)} /T _J	I _D = 250 μA, ref	to 25°C		-5.8		mV/°C
Drain-to-Source On Resistance	R _{DS(on)}	V _{GS} = 10 V	I _D = 50 A		1.25	1.5	mΩ
		V _{GS} = 4.5 V	I _D = 50 A		1.65	2.3	1
Gate-Resistance	R _G	T _A = 25°0	C		2		Ω
CHARGES & CAPACITANCES							
Input Capacitance	C _{ISS}	V_{GS} = 0 V, f = 1 MHz, V_{DS} = 25 V			6660		pF
Output Capacitance	C _{OSS}				3000		
Reverse Transfer Capacitance	C _{RSS}				45		
Total Gate Charge	Q _{G(TOT)}	V_{GS} = 4.5 V, V_{DS} = 30 V, I_{D} = 50 A			41		nC
Total Gate Charge	Q _{G(TOT)}	V_{GS} = 10 V, V_{DS} = 30 V, I_{D} = 50 A			91		
Gate-to-Source Charge	Q _{GS}				17		
Gate-to-Drain Charge	Q _{GD}				9		
Plateau Voltage	V _{GP}				2.9		V
SWITCHING CHARACTERISTICS (Note 3)							
Turn-On Delay Time	t _{d(ON)}	V_{GS} = 10 V, V_{DS} = 48 V, I_{D} = 50 A, R_{G} = 1 Ω			14.5		ns
Rise Time	t _r				55.6		1
Turn-Off Delay Time	t _{d(OFF)}				47.5		1
Fall Time	t _f				14.1		1
DRAIN-SOURCE DIODE CHARACTERISTIC	S						
Forward Diode Voltage	V _{SD}	$V_{GS} = 0 V,$	$T_J = 25^{\circ}C$		0.78	1.2	V
		I _S = 50 A	T _J = 125°C		0.66		1
Reverse Recovery Time	t _{RR}	V_{GS} = 0 V, dI _S /dt = 100 A/µs, I _S = 50 A			76		ns
Reverse Recovery Charge	Q _{RR}				130		nC

Product parametric performance is indicated in the Electrical Characteristics for the listed test conditions, unless otherwise noted. Product performance may not be indicated by the Electrical Characteristics if operated under different conditions. 3. Switching characteristics are independent of operating junction temperatures.

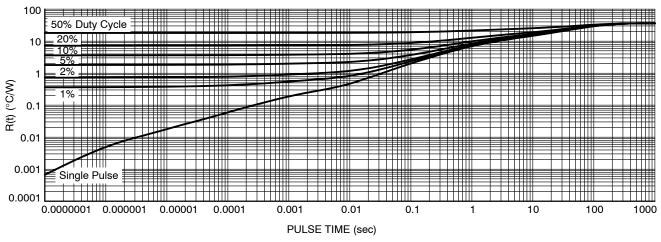
TYPICAL CHARACTERISTICS



TYPICAL CHARACTERISTICS



TYPICAL CHARACTERISTICS





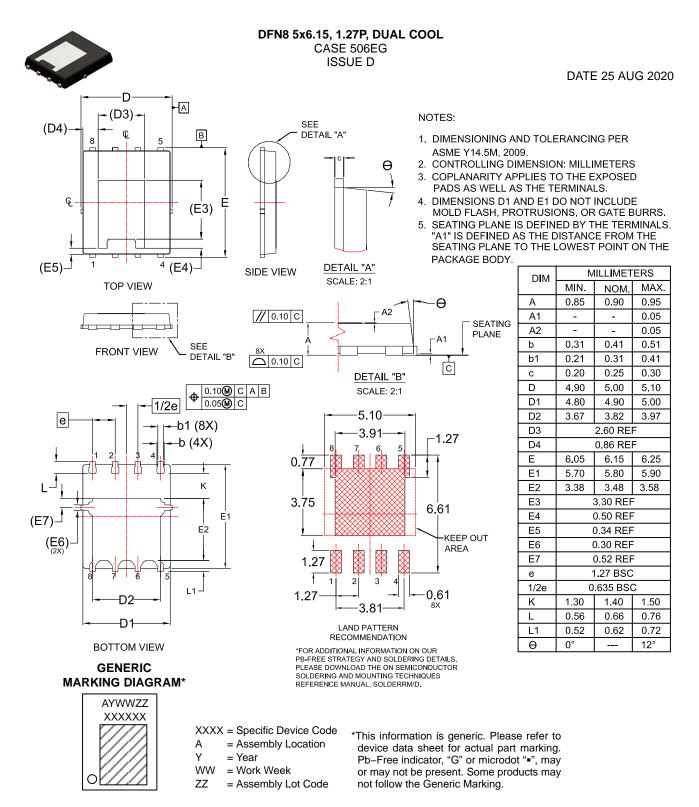
ORDERING INFORMATION

Device	Device Marking	Package	Shipping [†]
NVMFSC1D6N06CL	4H	DFN8 5x6 (Pb–Free/Halogen Free)	3000 / Tape & Reel

+For information on tape and reel specifications, including part orientation and tape sizes, please refer to our Tape and Reel Packaging Specifications Brochure, BRD8011/D.

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